

CONFIGURABLE MULTIPLE-FUNCTION GATE

Description

The 74LVC1G97 is a single 3-input positive configurable multiple function gate with a standard push-pull output. The output state is determined by eight patterns of 3-bit input. The user can chose the logic functions MUX, AND, OR, NAND, NOR, inverter or noninverting buffer. All inputs can be connected to ground or Vcc as required. The device is designed for operation with a power supply range of 1.65V to 5.5V. The inputs are tolerant to 5.5V allowing this device to be used in a mixed voltage environment. The device is fully specified for partial power down applications using IOFF. The IOFF circuitry disables the output preventing damaging current backflow when the device is powered down. The user is reminded that the device can simulate several types of logic gates but may respond differently due to the Schmitt action at the inputs.

Features

- Wide Supply Voltage Range from 1.65V to 5.5V
- ± 24mA Output Drive at 3.3V
- CMOS low power consumption
- IOFF Supports Partial-Power-Down Mode Operation
- Inputs accept up to 5.5V
- ESD Protection Exceeds JESD 22
 - 200-V Machine Model (A115-A)
 - 2000-V Human Body Model (A114-A)
- Latch-Up Exceeds 100mA per JESD 78, Class II
- Range of Package Options
- SOT26, SOT363, X2-DFN1410-6, and X2-DFN1010-6: Available
 - in "Green" Molding Compound (no Br, Sb)
 - Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
 - Halogen and Antimony Free. "Green" Device (Note 3)

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

See http://www.diodes.com for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

Pin Assignments



Applications

- Voltage Level Shifting
- General Purpose Logic
- Power Down Signal Isolation
- Wide array of products such as:
 - PCs, networking, notebooks, netbooks, PDAs
 - Computer peripherals, hard drives, CD/DVD ROM
 - TV, DVD, DVR, set top box
 - Cell Phones, Personal Navigation / GPS
 - MP3 players ,Cameras, Video Recorders



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Pin Descriptions

| Pin Name | Description |
|----------|----------------|
| IN1 | Data Input |
| GND | Ground |
| IN0 | Data Input |
| Y | Data Output |
| Vcc | Supply Voltage |
| IN2 | Data Input |

Logic Diagram



Function Table

| | Inputs | | Output |
|-----|--------|-----|--------|
| IN2 | IN1 | IN0 | Y |
| L | L | L | L |
| L | L | Н | L |
| L | Н | L | Н |
| L | Н | Н | Н |
| Н | L | L | L |
| Н | L | Н | н |
| н | Н | L | L |
| Н | Н | Н | Н |



CONFIGURABLE MULTIPLE-FUNCTION GATE



Configuration 6 Inverter

Configuration 5 2-Input OR Gate

| Function Selection T | able |
|---------------------------------------|---------------|
| Logic Function | Configuration |
| 2-to-1 Data Selector | 1 |
| 2-input AND gate | 2 |
| 2-input AND with inverted input | 3, 4 |
| 2-input NOR with inverted input | 3, 4 |
| 2-input OR | 5 |
| 2-input NOR with both inputs inverted | 2 |
| 1-input Inverter | 6 |



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Absolute Maximum Ratings (Note 4)

| Symbol | Description | Rating | Unit |
|------------------|---|------------------------------|------|
| ESD HBM | Human Body Model ESD Protection | 2 | KV |
| ESD MM | Machine Model ESD Protection | 200 | V |
| V _{CC} | Supply Voltage Range | -0.5 to 6.5 | V |
| VI | Input Voltage Range | -0.5 to 6.5 | V |
| Vo | Voltage applied to output in high impedance or IOFF state | -0.5 to 6.5 | V |
| Vo | Voltage applied to output in high or low state | -0.3 to V _{CC} +0.5 | V |
| I _{IK} | Input Clamp Current V _I < 0 | -50 | mA |
| loк | Output Clamp Current | -50 | mA |
| Ιο | Continuous output current | ±50 | mA |
| | Continuous current through Vdd or GND | ±100 | mA |
| TJ | Operating Junction Temperature | -40 to +150 | °C |
| T _{STG} | Storage Temperature | -65 to +150 | °C |

Notes: 4. Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.

Recommended Operating Conditions (Note 5)

| Symbol | | Parameter | Min | Max | Unit |
|-----------------|------------------------------------|---|------|-----------------|------|
| | On and the North and | Operating | 1.65 | 5.5 | V |
| Vcc | Operating Voltage | Data retention only | 1.5 | | V |
| VI | Input Voltage | | 0 | 5.5 | V |
| Vo | Output Voltage | | | V _{CC} | V |
| | | V _{CC} = 1.65V | | -4 | |
| | | V _{CC} = 2.3V | | -8 | |
| I _{OH} | High-level output current | V _{CC} = 3V | | -16 | mA |
| | | | | -24 | |
| | | V _{CC} = 4.5V | | -32 | |
| | | V _{CC} = 1.65V | | 4 | |
| | | $V_{CC} = 2.3V$ | | 8 | |
| IOL | Low-level output current | | | 16 | mA |
| | | $V_{CC} = 3V$ | | 24 | |
| | | V _{CC} = 4.5V | | 32 | |
| | | V _{CC} = 1.8V ± 0.15V, 2.5V ± 0.2V | | 20 | |
| Δt/ΔV | Input transition rise or fall rate | $V_{CC} = 3.3V \pm 0.3V$ | | 10 | ns/V |
| | | $V_{CC} = 5V \pm 0.5V$ | | 5 | |
| TA | Operating free-air temperature | | -40 | +125 | °C |

Notes: 5. Unused inputs should be held at V_{CC} or Ground.



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Electrical Characteristics $T_A = -40^{\circ}C$ to $+85^{\circ}C$ (All typical values are at $V_{CC} = 3.3V$, $T_A = +25^{\circ}C$)

| Symbol | Parameter | Test Conditions | Vcc | Min | Тур | Max | Unit |
|--|----------------------------|---|---------------|-----------------------|-----|------|------|
| | | | 1.65V | 0.70 | | 1.20 | |
| | | | 2.3V | 1.11 | | 1.60 | |
| V_{T+} | 0 0 1 | | ЗV | 1.50 | | 2.00 | |
| | theshold voltage | | 4.5V | 2.16 | | 2.74 | |
| | | | 5.5V | 2.61 | | 3.33 | |
| | | | 1.65V | 0.30 | | 0.72 | |
| | | | 2.3V | 0.58 | | 1.00 | |
| V _T - | | | 3V | 0.80 | | 1.30 | |
| | theshold voltage | | 4.5V | 1.21 | | 1.95 | |
| $V_{T*} = \begin{array}{ c c c c c } Positive-going input threshold voltage & 2.3V & 3V &$ | 1.45 | | 2.35 | | | | |
| | | | 1.65V | 0.30 | | 0.62 | |
| | | | 2.3V | 0.40 | | 0.80 | |
| ΔV_{T} | | | ЗV | 0.35 | | 1.00 | |
| | (V +- V -) | | 4.5V | 0.55 | | 1.10 | |
| | | | 5.5V | 0.60 | | 1.20 | |
| | | I _{OH} = -100μA | 1.65V to 5.5V | V _{CC} - 0.1 | | | |
| | | I _{OH} = -4mA | 1.65V | 1.2 | | | |
| | | I _{OH} = -8mA | 2.3V | 1.9 | | | |
| VOH | High Level Output Voltage | I _{OH} = -16mA | 0)/ | 2.4 | | | V |
| | | I _{OH} = -24mA | 3V | 2.3 | | | |
| | | I _{OH} = -32mA | 4.5V | 3.8 | | | |
| | | I _{OL} = 100μA | 1.65V to 5.5V | | | 0.1 | |
| | | $I_{OL} = 4mA$ | 1.65V | | | 0.45 | |
| V | | I _{OL} = 8mA | 2.3V | | | 0.3 | V |
| VOL | Hign-level input voltage | I _{OL} = 16mA | 2) (| | | 0.4 | v |
| | | $I_{OL} = 24 \text{mA}$ | 3V | | | 0.55 | |
| | | I _{OL} = 32mA | 4.5V | | | 0.55 | |
| l _l | Input Current | V _I = 5.5V or GND | 0 to 5.5V | | | ± 5 | μA |
| I _{OFF} | Power Down Leakage Current | $V_{\rm I}$ or $V_{\rm O} = 5.5 V$ | 0 | | | ± 10 | μA |
| Icc | Supply Current | | 1.65V to 5.5V | | | 10 | μA |
| ΔI _{CC} | Additional Supply Current | One input at V_{CC} –0.6V Other inputs at V_{CC} or GND | 3V to 5.5V | | | 500 | μA |



CONFIGURABLE MULTIPLE-FUNCTION GATE

Electrical Characteristics $T_A = -40^{\circ}C$ to $+125^{\circ}C$ (All typical values are at $V_{CC} = 3.3V$, $T_A = +25^{\circ}C$)

| Symbol | Parameter | Test Conditions | Vcc | Min | Тур | Max | Unit |
|---|----------------------------|---|---------------|----------------------|------|-------|------|
| | | | 1.65V | 0.70 | | 1.20 | |
| | | | 2.3V | 1.11 | | 1.60 | |
| V_{T+} | | | 3V | 1.50 | | 2.00 | |
| | threshold voltage | | 4.5V | 2.16 | | 2.74 | |
| | | | 5.5V | 2.61 | | 3.33 | |
| | | | 1.65V | 0.30 | | 0.75 | |
| | | | 2.3V | 0.58 | | 1.03 | |
| V _{T-} | | | 3V | 0.80 | | 1.33 | |
| | Infestioid voltage | | 4.5V | 1.21 | | 1.95 | |
| Intreshold voltageVT.Negative-going input threshold voltage ΔV_T Hysteresis $(V_{T+} - V_{T-})$ VOHHigh Level Output VoltageVOHIOH = -100µA IOH = -4mA IOH = -4mA IOH = -16mA IOH = -24mA IOH = -32mAVOLHigh-level Input VoltageVOLIOL = 100µA IOL = 16mA IOL = 16mA IOL = 24mA IOL = 16mAIOL = 24mA IOL = 32mAIIInput CurrentVI = 5.5V or G IOFFIOFFPower Down Leakage CurrentVI or VO = 5.51 | | 5.5V | 1.45 | | 2.35 | | |
| | | | 1.65V | 0.30 | | 0.62 | |
| | | | 2.3V | 0.37 | | 0.80 | |
| ΔV_T | | | 3V | 0.32 | | 1.00 | |
| | (VT+ - VT-) | | 4.5V | 0.50 | | 1.20 | |
| | | | 5.5V | 0.55 | | 1.40 | |
| | | I _{OH} = -100μA | 1.65V to 5.5V | V _{CC} -0.1 | | | |
| | | I _{OH} = -4mA | 1.65V | 0.95 | | | |
| | | I _{OH} = -8mA | 2.3V | 1.7 | | | ., |
| VOH | High Level Output Voltage | I _{OH} = -16mA | 014 | 1.9 | | | V |
| | | I _{OH} = -24mA | 3V | 2.0 | | | |
| | | I _{OH} = -32mA | 4.5V | 3.4 | | | |
| | | I _{OL} = 100μA | 1.65V to 5.5V | | | 0.1 | |
| | | $I_{OL} = 4mA$ | 1.65V | | | 0.7 | |
| | | I _{OL} = 8mA | 2.3V | | | 0.45 | ., |
| VOL | High-level Input Voltage | I _{OL} = 16mA | 014 | | | 0.6 | V |
| | | $I_{OL} = 24 \text{mA}$ | 3V | | | 0.8 | |
| | | I _{OL} = 32mA | 4.5V | | | 0.8 | |
| II. | Input Current | $V_I = 5.5V$ or GND | 0 to 5.5V | | | ± 100 | μA |
| I _{OFF} | Power Down Leakage Current | $V_{I} \text{ or } V_{O} = 5.5 V$ | 0 | | | ± 200 | μA |
| I _{CC} | Supply Current | V _I = 5.5V of GND I _O =0 | 1.65V to 5.5V | | | 200 | μA |
| ΔI _{CC} | Additional Supply Current | One input at V_{CC} -0.6V Other inputs at V_{CC} or GND | 3V to 5.5V | | | 5000 | μA |



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Electrical Characteristics (All typical values are at $V_{CC} = 3.3V$, $T_A = +25^{\circ}C$)

| Symbol | Parameter | Test Conditions | Vcc | Min | Тур | Max | Unit |
|-----------------------------|--|-------------------------|----------|-----|-----|---------|------|
| Cı | Input Capacitance | $V_1 = V_{CC} - or GND$ | 3.3 | | 3.5 | | pF |
| | θ _{JA} Thermal Resistance Junction- to-Ambient S | SOT26 | | | 204 | | |
| Thermal Resistance Junction | SOT363 | | | 371 | | 0.0.0.0 | |
| θ_{JA} | to-Ambient | X2-DFN1410-6 | (Note 6) | | 430 | | °C/W |
| | | X2-DFN1010-6 | | | 510 | | |
| | | SOT26 | | | 52 | | |
| | Thermal Resistance Junction- | SOT363 | | | 143 | | |
| θ_{JC} | to-Case | X2-DFN1410-6 | (Note 6) | | 190 | | °C/W |
| | | X2-DFN1010-6 | | | 250 | | |

Notes: 6. Test condition for SOT26, SOT363, X2-DFN1410-6 and X2-DFN1010-6 : Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.

Switching Characteristics

| T _A = -40°C to +85 | 5° C , C _L = 30 or 5 | 0pF as noted (se | e Figure 1) |
|-------------------------------|--|------------------|-------------|
| | | | |

| Parameter | From | то | | = 1.8V .15V | | = 2.5V).2V | | = 3.3V).3V | | = 5V 0.5V | Unit |
|-----------------|------------------|----------|-----|----------------|-----|----------------|-----|----------------|-----|--------------|------|
| | (Input) (OUTPUT) | (OUTPUT) | Min | Max | Min | Max | Min | Max | Min | Max | |
| t _{pd} | Any | Y | 1.0 | 14.4 | 0.7 | 8.3 | 0.7 | 6.3 | 0.7 | 5.1 | ns |

$T_A = -40^{\circ}C \text{ to } +125^{\circ}C$, $C_L = 30 \text{ or } 50\text{pF}$ as noted (see Figure 1)

| Parameter | From | то | | = 1.8V .15V | | = 2.5V).2V | | = 3.3V).3V | | = 5V).5V | Unit |
|-----------------|------------------|----------|-----|----------------|-----|----------------|-----|----------------|-----|--------------|------|
| | (Input) (OUTPUT) | (OUTPUT) | Min | Max | Min | Max | Min | Max | Min | Max | |
| t _{pd} | Any | Y | 1.0 | 18.0 | 0.7 | 10.4 | 0.7 | 7.9 | 0.7 | 6.4 | ns |

Operating Characteristics

T_A = +25°C

| Parameter | | Test Conditions | V _{CC} = 1.8V Typ. | V _{CC} = 2.5V Typ. | V _{CC} = 3.3V Typ. | V _{CC} = 5V Typ. | Unit |
|-----------------|-------------------------------|--------------------|--------------------------------|--------------------------------|--------------------------------|------------------------------|------|
| C _{pd} | Power dissipation capacitance | f = 10 MHz | 22 | 22 | 23 | 24 | pF |



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Parameter Measurement Information



| Vcc | Inj | outs | VM | CL | RL |
|------------|-----------------|--------------------------------|--------------------|------|------|
| | VI | t _r /t _f | - 111 | 61 | |
| 1.8V±0.15V | V _{CC} | ≤2ns | V _{CC} /2 | 30pF | 1ΚΩ |
| 2.5V±0.2V | V _{CC} | ≤2ns | V _{CC} /2 | 30pF | 500Ω |
| 3.3V±0.3V | 3V | ≤2.5ns | 1.5V | 50pF | 500Ω |
| 5V±0.5V | V _{CC} | ≤2.5ns | V _{CC} /2 | 50pF | 500Ω |



Voltage Waveform Pulse Duration



Voltage Waveform Propagation Delay Times Inverting and Non Inverting Outputs

Figure 1. Load Circuit and Voltage Waveforms

Notes:

- A. Includes test lead and test apparatus capacitance.
- B. All pulses are supplied at pulse repetition rate \leq 10 MHz
- C. Inputs are measured separately one transition per measurement
- D. t_{PLH} and t_{PHL} are the same as t_{PD}



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Notes: 7. Pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.



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Marking Information

(1) SOT26, SOT363



| Part Number | Package | Identification Code |
|-------------|---------|---------------------|
| 74LVC1G97W6 | SOT26 | TY |
| 74LVC1G97DW | SOT363 | TY |

(2) X2-DFN1010-6, X2-DFN1410-6



| Part Number | Package | Identification Code |
|--------------|--------------|---------------------|
| 74LVC1G97FW4 | X2-DFN1010-6 | TY |
| 74LVC1G97FZ4 | X2-DFN1410-6 | TY |



CONFIGURABLE MULTIPLE-FUNCTION GATE

Package Outline Dimensions (All Dimensions in mm)

(1) SOT26



| SOT26 | | | | |
|----------------------|-------|------|------|--|
| Dim | Min | Max | Тур | |
| Α | 0.35 | 0.50 | 0.38 | |
| в | 1.50 | 1.70 | 1.60 | |
| с | 2.70 | 3.00 | 2.80 | |
| D | | | 0.95 | |
| Н | 2.90 | 3.10 | 3.00 | |
| J | 0.013 | 0.10 | 0.05 | |
| κ | 1.00 | 1.30 | 1.10 | |
| 1 | 0.35 | 0.55 | 0.40 | |
| Μ | 0.10 | 0.20 | 0.15 | |
| ರ | 0° | 8° | | |
| All Dimensions in mm | | | | |

(2) SOT363



| | SOT363 | | | |
|----------------------|--------|------|--|--|
| Dim | Min | Max | | |
| Α | 0.10 | 0.30 | | |
| в | 1.15 | 1.35 | | |
| С | 2.00 | 2.20 | | |
| D | 0.65 | Тур | | |
| F | 0.40 | 0.45 | | |
| H | 1.80 | 2.20 | | |
| J | 0 | 0.10 | | |
| ĸ | 0.90 | 1.00 | | |
| L | 0.25 | 0.40 | | |
| М | 0.10 | 0.22 | | |
| α | 0° | 8° | | |
| All Dimensions in mm | | | | |



CONFIGURABLE MULTIPLE-FUNCTION GATE

Package Outline Dimensions (All Dimensions in mm)

(3) X2-DFN1010-6





| | X2-DFN1010-6 | | | |
|-----|----------------------|------|-------|--|
| Dim | Min | Max | Тур | |
| Α | — | 0.40 | 0.39 | |
| A1 | 0.00 | 0.05 | 0.02 | |
| A3 | | | 0.13 | |
| b | 0.14 | 0.20 | 0.17 | |
| b1 | 0.05 | 0.15 | 0.10 | |
| D | 0.95 | 1.05 | 1.00 | |
| Е | 0.95 | 1.05 | 1.00 | |
| е | _ | _ | 0.35 | |
| L | 0.35 | 0.45 | 0.40 | |
| к | 0.15 | | | |
| Z | _ | | 0.065 | |
| All | All Dimensions in mm | | | |

(4) X2-DFN1410-6



| X2-DFN1410-6 | | | | |
|----------------------|-----------------|-------|-------|--|
| Dim | Dim Min Max Typ | | | |
| Α | | 0.40 | 0.39 | |
| A1 | 0.00 | 0.05 | 0.02 | |
| A3 | | | 0.13 | |
| b | 0.15 | 0.25 | 0.20 | |
| D | 1.35 | 1.45 | 1.40 | |
| Е | 0.95 | 1.05 | 1.00 | |
| е | | | 0.50 | |
| L | 0.25 | 0.35 | 0.30 | |
| Z | | _ | 0.10 | |
| Z1 | 0.045 | 0.105 | 0.075 | |
| All Dimensions in mm | | | | |



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Suggest Pad Layout

(1) SOT26



| Dimensions | Value (in mm) |
|------------|---------------|
| Z | 3.20 |
| G | 1.60 |
| х | 0.55 |
| Y | 0.80 |
| C1 | 2.40 |
| C2 | 0.95 |

(2) SOT363



| Dimensions | Value (in mm) |
|------------|---------------|
| Z | 2.5 |
| G | 1.3 |
| Х | 0.42 |
| Y | 0.6 |
| C1 | 1.9 |
| C2 | 0.65 |

(3) X2-DFN1010-6



| Dimensions | Value (in mm) |
|------------|------------------|
| С | 0.350 |
| G | 0.150 |
| Х | 0.200 |
| X1 | 0.900 |
| Y | 0.550 |
| Y1 | 1.250 |



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Suggest Pad Layout

(4) X2-DFN1410-6



| Dimensions | Value (in mm) |
|------------|------------------|
| C | 0.500 |
| G | 0.250 |
| Х | 0.250 |
| X1 | 1.250 |
| Y | 0.525 |
| Y1 | 1.250 |



CONFIGURABLE MULTIPLE-FUNCTION GATE

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